July 2007

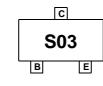


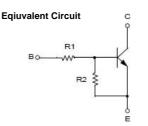
FJY3003R NPN Epitaxial Silicon Transistor

Features

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R1=22KΩ, R2=22KΩ)
- Complement to FJY4003R







Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|---|---------|-------|
| V _{CBO} | Collector-Base Voltage | 50 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 10 | V |
| I _C | Collector Current | 100 | mA |
| T _{STG} | Storage Temperature Range | -55~150 | °C |
| TJ | Junction Temperature | 150 | °C |
| P _C | Collector Power Dissipation, by $R_{\theta JA}$ | 200 | mW |

These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

Thermal Characteristics* Ta=25°C unless otherwise noted

| Symbol | Parameter | Мах | Units |
|----------------|---|-----|-------|
| R_{\thetaJA} | Thermal Resistance, Junction to Ambient | 600 | °C/W |

* Minimum land pad size.

Electrical Characteristics* T_c = 25°C unless otherwise noted

| Parameter | Test Condition | MIN | Тур | MAX | Units |
|--------------------------------------|---|---|---|---|--|
| Collector-Emitter Breakdown Voltage | Ic = 10 uA, IE = 0 | 50 | | | V |
| Collector-Base Breakdown Voltage | Ic = 100 uA, I _B = 0 | 50 | | | V |
| Collector-Cutoff Current | $V_{CB} = 40 V, I_E = 0$ | | | 0.1 | uA |
| DC Current Gain | Vce = 5 V, Ic = 5 mA | 56 | | | |
| Collector-Emitter Saturation Voltage | Ic = 10 mA, I _B = 0.5 mA | | | 0.3 | V |
| Current Gain - Bandwidth Product | Vce = 10V, Ic = 5 mA | | 250 | | MHz |
| Output Capacitance | Vcb = 10 V, IE = 0, f = 1.0 MHz | | 3.7 | | pF |
| Input Off Voltage | Vce = 5 V, Ic = 100uA | 0.5 | | | V |
| Input On Voltage | Vce = 0.3V, Ic = 5mA | | | 3 | V |
| Input Resistor | | 15 | 22 | 29 | KΩ |
| Resistor Ratio | | 0.9 | 1.0 | 1.1 | |
| | Collector-Emitter Breakdown Voltage Collector-Base Breakdown Voltage Collector-Cutoff Current DC Current Gain Collector-Emitter Saturation Voltage Current Gain - Bandwidth Product Output Capacitance Input Off Voltage Input On Voltage Input Resistor | Collector-Emitter Breakdown VoltageIc = 10 uA, IE = 0Collector-Base Breakdown VoltageIc = 100 uA, IB = 0Collector-Cutoff CurrentVcB = 40 V, IE = 0DC Current GainVcE = 5 V, Ic = 5 mACollector-Emitter Saturation VoltageIc = 10 mA, IB = 0.5 mACurrent Gain - Bandwidth ProductVcE = 10V, Ic = 5 mAOutput CapacitanceVcB = 10 V, IE = 0, f = 1.0 MHzInput Off VoltageVcE = 5 V, Ic = 100uAInput ResistorVcE = 0.3V, Ic = 5mA | Collector-Emitter Breakdown VoltageIc = 10 uA, IE = 050Collector-Base Breakdown VoltageIc = 100 uA, IE = 050Collector-Base Breakdown VoltageIc = 100 uA, IE = 050Collector-Cutoff CurrentVcB = 40 V, IE = 050DC Current GainVcE = 5 V, Ic = 5 mA56Collector-Emitter Saturation VoltageIc = 10 mA, IB = 0.5 mA56Current Gain - Bandwidth ProductVcE = 10V, Ic = 5 mA56Output CapacitanceVcB = 10 V, IE = 0, f = 1.0 MHz11Input Off VoltageVcE = 5 V, Ic = 100uA0.5Input On VoltageVcE = 0.3V, Ic = 5mA15 | Collector-Emitter Breakdown VoltageIc = 10 uA, IE = 050Collector-Base Breakdown VoltageIc = 100 uA, IB = 050Collector-Base Breakdown VoltageIc = 100 uA, IB = 050Collector-Cutoff CurrentVcB = 40 V, IE = 050DC Current GainVcE = 5 V, Ic = 5 mA56Collector-Emitter Saturation VoltageIc = 10 mA, IB = 0.5 mA56Current Gain - Bandwidth ProductVcE = 10V, Ic = 5 mA250Output CapacitanceVcB = 10 V, IE = 0, f = 1.0 MHz3.7Input Off VoltageVcE = 5 V, Ic = 100uA0.5Input On VoltageVcE = 0.3V, Ic = 5mA15Input Resistor1522 | Collector-Emitter Breakdown VoltageIc = 10 uA, IE = 050Collector-Base Breakdown VoltageIc = 10 uA, IB = 050Collector-Cutoff CurrentVcB = 40 V, IE = 00.1DC Current GainVcE = 5 V, Ic = 5 mA56Collector-Emitter Saturation VoltageIc = 10 mA, IB = 0.5 mA0.3Current Gain - Bandwidth ProductVcE = 10V, Ic = 5 mA250Output CapacitanceVcB = 10 V, IE = 0, f = 1.0 MHz3.7Input Off VoltageVcE = 5 V, Ic = 5mA0.5Input On VoltageVcE = 0.3V, Ic = 5mA3Input Resistor152229 |

Typical Performance Characteristics

Figure 1. DC current Gain

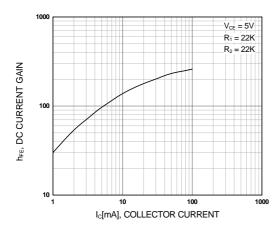


Figure 2. Input On Voltage

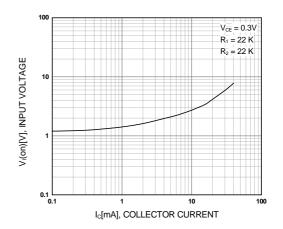


Figure 3. Input off Voltage

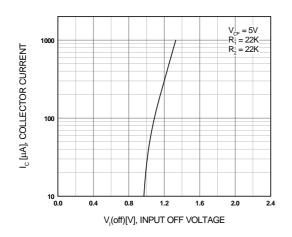
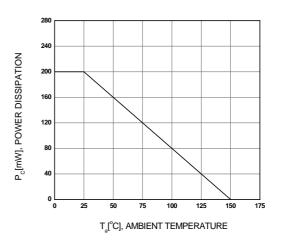
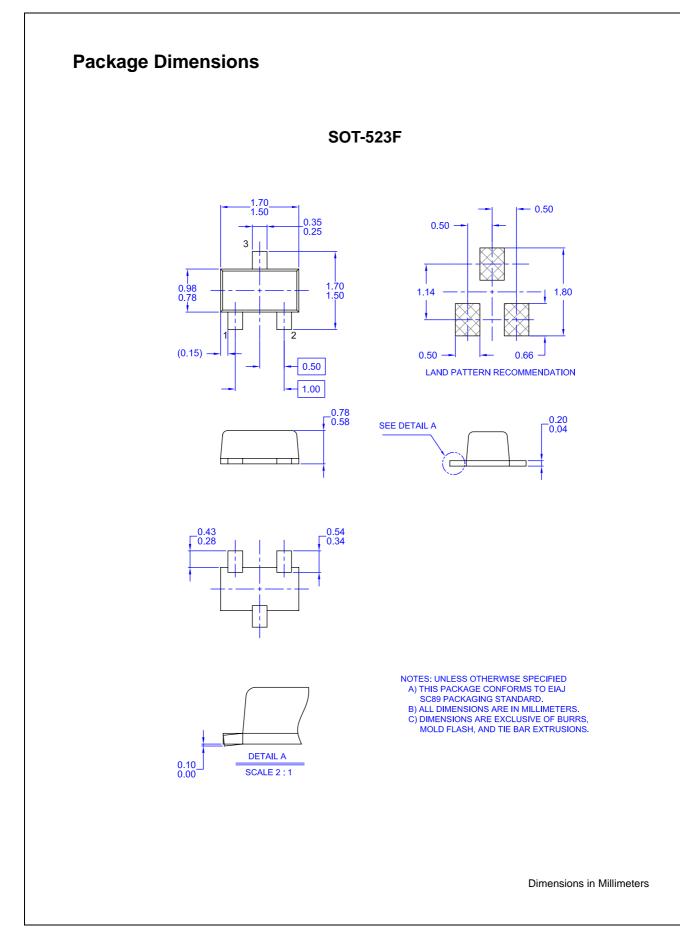


Figure 4. Power Derating





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| EnSigna™ | OCXPro™ | STEALTH™ |
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